

# RJH60M3DPQ-A0

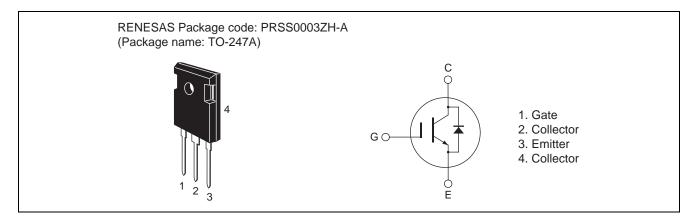
600 V - 17 A - IGBT Application: Inverter

R07DS0534EJ0100 Rev.1.00 Sep 02, 2011

#### **Features**

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage  $V_{CE(sat)}=1.8~V$  typ. (at  $I_C=17~A,~V_{GE}=15~V,~Ta=25^{\circ}C$ )
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching  $t_f=80 \text{ ns typ. (at $V_{CC}=300$ V, $V_{GE}=15$ V, $I_C=17$ A, $Rg=5$ $\Omega$, $Ta=25^{\circ}$C)}$

### **Outline**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	600	V
Gate to emitter voltage		V <sub>GES</sub>	±30	V
Collector current	Tc = 25°C	I <sub>C</sub>	35	Α
	Tc = 100°C	I <sub>C</sub>	17	А
Collector peak current		ic(peak) Note1	70	А
Collector to emitter diode forward current		i <sub>DF</sub>	17	А
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) Note1	70	А
Collector dissipation		P <sub>C</sub> Note2	(127)	W
Junction to case thermal resistance (IGBT)		θj-c Note2	(0.98)	°C/W
Junction to case thermal resistance (Diode)		θj-cd Note2	2.3	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu s, \, duty \, cycle \leq$  1%

2. Value at Tc = 25°C

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# **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

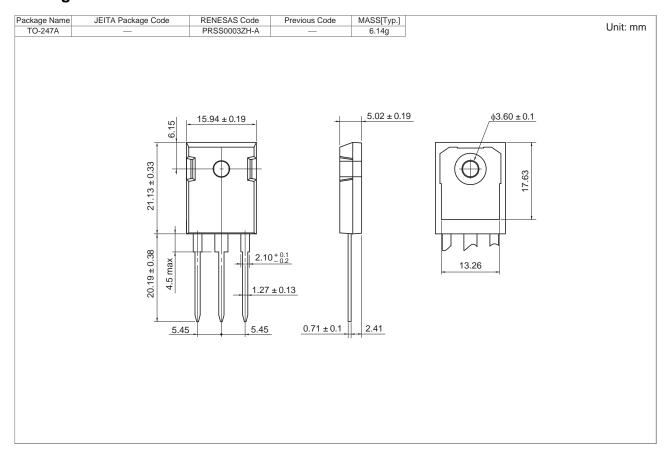
 $diF/dt = 100 A/\mu s$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I <sub>CES</sub> / I <sub>R</sub>	_	_	5	μΑ	$V_{CE} = 600 \text{ V}, V_{GE} = 0$
/ Diode reverse current						
Gate to emitter leak current	I <sub>GES</sub>			±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	5	_	7	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	1.8	2.3	V	$I_C = 17 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
	V <sub>CE(sat)</sub>	_	2.2	_	V	$I_C = 35 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies	_	900	_	pF	V <sub>CE</sub> = 25 V V <sub>GE</sub> = 0
Output capacitance	Coes	_	60	_	pF	
Reverse transfer capacitance	Cres	_	30	_	pF	f = 1 MHz
Total gate charge	Qg	_	36	_	nC	V <sub>GE</sub> = 15 V
Gate to emitter charge	Qge	_	6	_	nC	V <sub>CE</sub> = 300 V
Gate to collector charge	Qgc	_	16	_	nC	I <sub>C</sub> = 17 A
Switching time	t <sub>d(on)</sub>	_	30	_	ns	$V_{CC} = 300 \text{ V}, V_{GE} = 15 \text{ V}$ $I_{C} = 17 \text{ A}$ $Rg = 5 \Omega$
	t <sub>r</sub>	_	15	_	ns	
	t <sub>d(off)</sub>	_	80	_	ns	
	t <sub>f</sub>	_	80	_	ns	Inductive load
Short circuit withstand time	t <sub>sc</sub>	6	8	_	μS	Tc = 100 °C
						$V_{CC} \le 360 \text{ V}, V_{GE} = 15 \text{ V}$
FRD Forward voltage	$V_{F}$	_	1.3	1.7	V	I <sub>F</sub> = 17 A <sup>Note3</sup>
FRD reverse recovery time	t <sub>rr</sub>	_	100	_	ns	I <sub>F</sub> = 17 A

Notes: 3. Pulse test.

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# **Package Dimension**



# **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJH60M3DPQ-A0-T0	240 pcs	Box (Tube)

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